NSN 5961-00-189-2940

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-189-2940 **Inclosure Material:** Metal **Overall Length:** 0.535 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and mounting hardware **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 7.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 12.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No